

# MMBT2369LT1, MMBT2369ALT1

MMBT2369ALT1 is a Preferred Device

## Switching Transistors

### NPN Silicon

#### Features

- Pb-Free Packages are Available

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	15	Vdc
Collector-Emitter Voltage	$V_{CES}$	40	Vdc
Collector-Base Voltage	$V_{CBO}$	40	Vdc
Emitter-Base Voltage	$V_{EBO}$	4.5	Vdc
Collector Current - Continuous	$I_C$	200	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

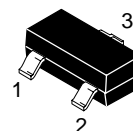
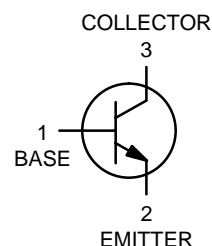
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.



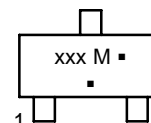
ON Semiconductor®

<http://onsemi.com>



SOT-23  
CASE 318  
STYLE 6

#### MARKING DIAGRAMS



xxx = M1J or 1JA  
M = Date Code\*  
■ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### ORDERING INFORMATION

Device	Package	Shipping
MMBT2369LT1	SOT-23	3000/Tape & Reel
MMBT2369LT1G	SOT-23 (Pb-Free)	3000/Tape & Reel
MMBT2369ALT1	SOT-23	3000/Tape & Reel
MMBT2369ALT1G	SOT-23 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

# MMBT2369LT1, MMBT2369ALT1

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Collector–Emitter Breakdown Voltage (Note 3) (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	15	–	–	Vdc
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 10 μAdc, V <sub>BE</sub> = 0)	V <sub>(BR)CES</sub>	40	–	–	Vdc
Collector–Base Breakdown Voltage (I <sub>C</sub> = 10 μAdc, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	40	–	–	Vdc
Emitter–Base Breakdown Voltage (I <sub>E</sub> = 10 μAdc, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	4.5	–	–	Vdc
Collector Cutoff Current (V <sub>CB</sub> = 20 Vdc, I <sub>E</sub> = 0) (V <sub>CB</sub> = 20 Vdc, I <sub>E</sub> = 0, T <sub>A</sub> = 150°C)	I <sub>CBO</sub>	–	–	0.4 30	μAdc
Collector Cutoff Current (V <sub>CE</sub> = 20 Vdc, V <sub>BE</sub> = 0)	I <sub>CES</sub>	–	–	0.4	μAdc

## ON CHARACTERISTICS

DC Current Gain (Note 3) (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 1.0 Vdc) (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 1.0 Vdc) (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 0.35 Vdc) (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 0.35 Vdc, T <sub>A</sub> = –55°C) (I <sub>C</sub> = 30 mAdc, V <sub>CE</sub> = 0.4 Vdc) (I <sub>C</sub> = 100 mAdc, V <sub>CE</sub> = 2.0 Vdc) (I <sub>C</sub> = 100 mAdc, V <sub>CE</sub> = 1.0 Vdc)	MMBT2369 MMBT2369A MMBT2369A MMBT2369A MMBT2369A MMBT2369 MMBT2369A	h <sub>FE</sub>	40 – 40 20 30 20 20	– – – – – – –	120 120 – – – – –	–
Collector–Emitter Saturation Voltage (Note 3) (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 1.0 mAdc) (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 1.0 mAdc) (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 1.0 mAdc, T <sub>A</sub> = +125°C) (I <sub>C</sub> = 30 mAdc, I <sub>B</sub> = 3.0 mAdc) (I <sub>C</sub> = 100 mAdc, I <sub>B</sub> = 10 mAdc)	MMBT2369 MMBT2369A MMBT2369A MMBT2369A MMBT2369A	V <sub>CE(sat)</sub>	– – – – –	– – – – –	0.25 0.20 0.30 0.25 0.50	Vdc
Base–Emitter Saturation Voltage (Note 3) (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 1.0 mAdc) (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 1.0 mAdc, T <sub>A</sub> = –55°C) (I <sub>C</sub> = 30 mAdc, I <sub>B</sub> = 3.0 mAdc) (I <sub>C</sub> = 100 mAdc, I <sub>B</sub> = 10 mAdc)	MMBT2369A MMBT2369A MMBT2369A MMBT2369A	V <sub>BE(sat)</sub>	0.7 – – –	– – – –	0.85 1.02 1.15 1.60	Vdc

## SMALL-SIGNAL CHARACTERISTICS

Output Capacitance (V <sub>CB</sub> = 5.0 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>obo</sub>	–	–	4.0	pF
Small Signal Current Gain (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc, f = 100 MHz)	h <sub>fe</sub>	5.0	–	–	–

## SWITCHING CHARACTERISTICS

Storage Time (I <sub>B1</sub> = I <sub>B2</sub> = I <sub>C</sub> = 10 mAdc)	t <sub>s</sub>	–	5.0	13	ns
Turn–On Time (V <sub>CC</sub> = 3.0 Vdc, I <sub>C</sub> = 10 mAdc, I <sub>B1</sub> = 3.0 mAdc)	t <sub>on</sub>	–	8.0	12	ns
Turn–Off Time (V <sub>CC</sub> = 3.0 Vdc, I <sub>C</sub> = 10 mAdc, I <sub>B1</sub> = 3.0 mAdc, I <sub>B2</sub> = 1.5 mAdc)	t <sub>off</sub>	–	10	18	ns

3. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

# MMBT2369LT1, MMBT2369ALT1

## SWITCHING TIME EQUIVALENT TEST CIRCUITS FOR 2N2369, 2N3227

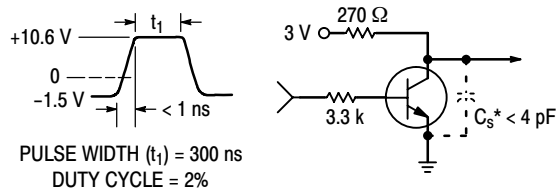


Figure 1.  $t_{on}$  Circuit – 10 mA

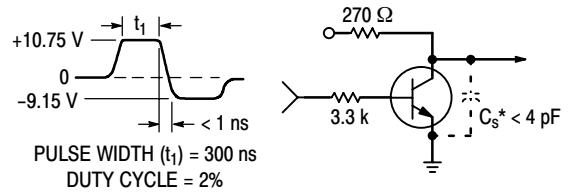


Figure 3.  $t_{off}$  Circuit – 10 mA

\*Total shunt capacitance of test jig and connectors.

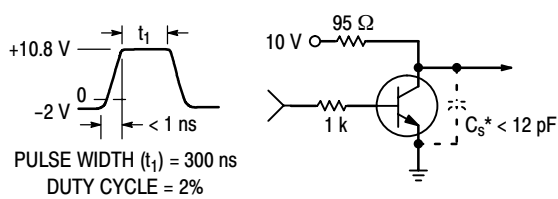


Figure 2.  $t_{on}$  Circuit – 100 mA

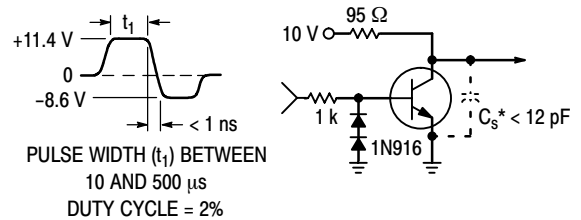
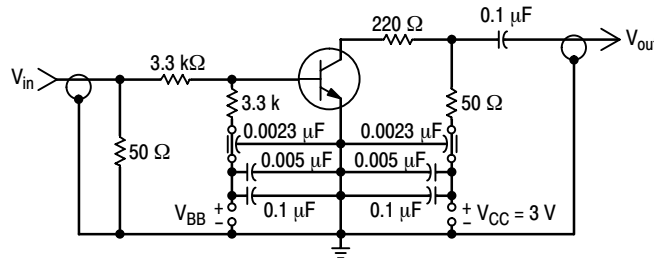
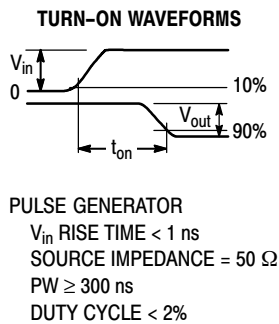


Figure 4.  $t_{off}$  Circuit – 100 mA

\*Total shunt capacitance of test jig and connectors.



TO OSCILLOSCOPE  
 INPUT IMPEDANCE =  $50\ \Omega$   
 RISE TIME = 1 ns

### TURN-OFF WAVEFORMS

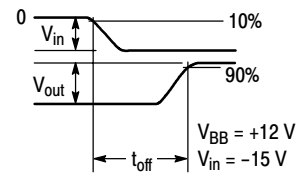


Figure 5. Turn-On and Turn-Off Time Test Circuit



# MMBT2369LT1, MMBT2369ALT1

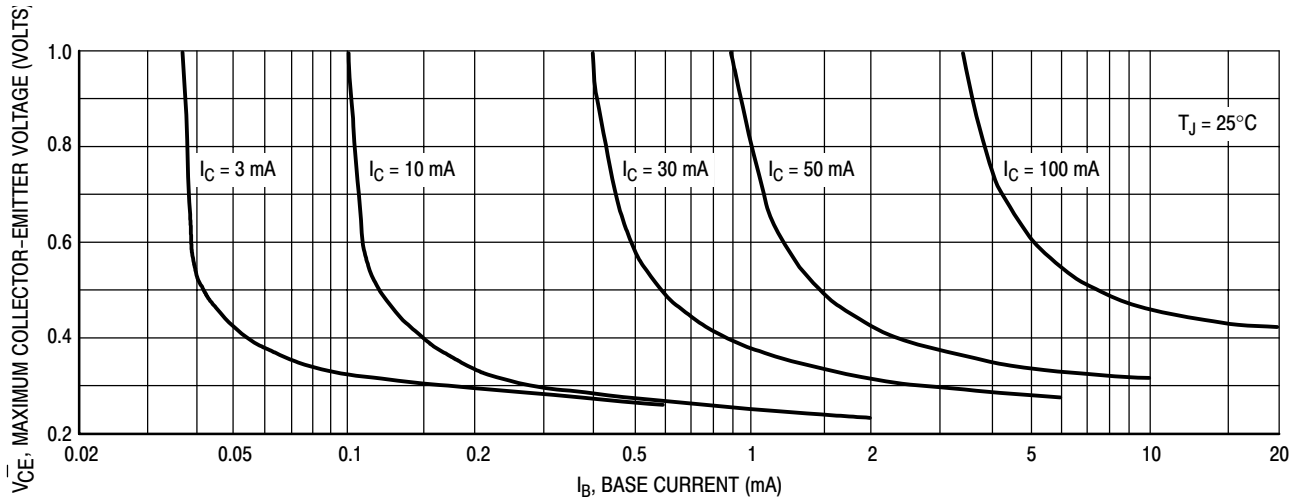


Figure 12. Maximum Collector Saturation Voltage Characteristics

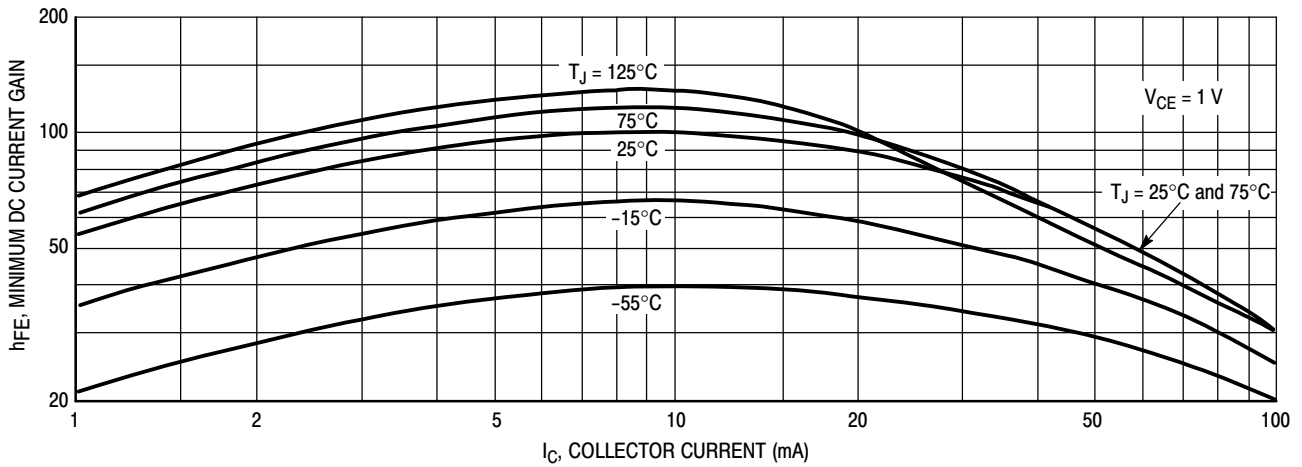


Figure 13. Minimum Current Gain Characteristics

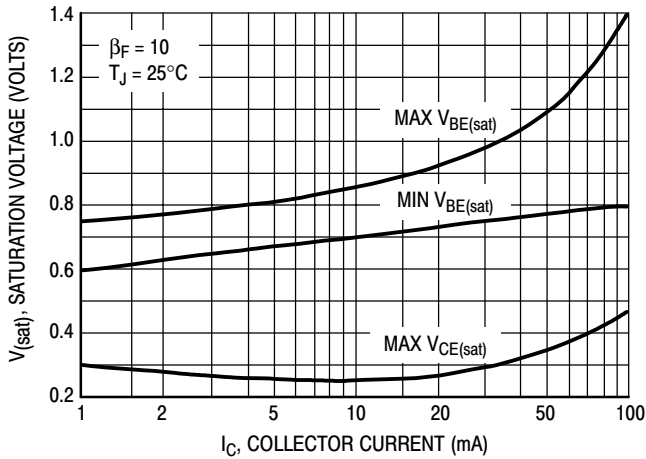


Figure 14. Saturation Voltage Limits

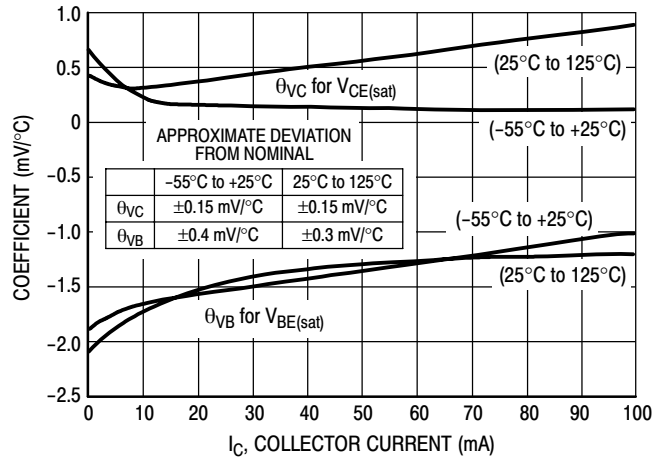
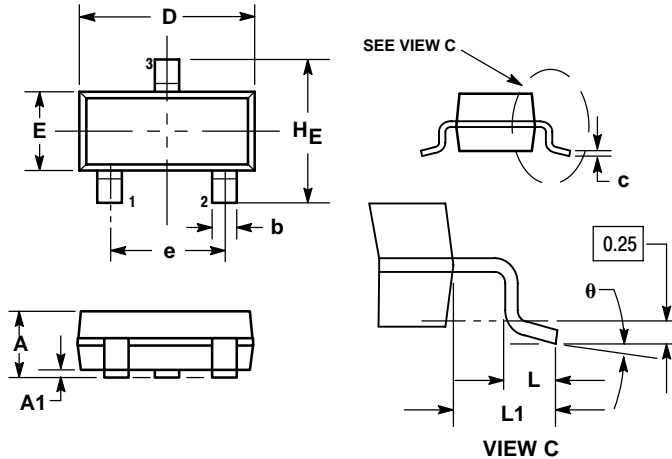


Figure 15. Typical Temperature Coefficients

# MMBT2369LT1, MMBT2369ALT1

## PACKAGE DIMENSIONS

SOT-23 (TO-236)  
CASE 318-08  
ISSUE AN



### NOTES:

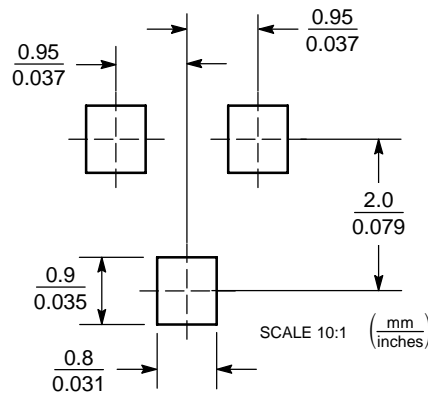
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

### STYLE 6:

1. BASE
2. EMITTER
3. COLLECTOR

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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